

## DUAL 4-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER WITH LATCH

## FEATURES

- Wide analog input voltage range:  $\pm 5\text{ V}$
- Low "ON" resistance:  
80  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 4.5\text{ V}$   
70  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 6.0\text{ V}$   
60  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 9.0\text{ V}$
- Logic level translation:  
to enable 5 V logic to communicate  
with  $\pm 5\text{ V}$  analog signals
- Typical "break before make" built in
- Address latches provided
- Output capability: non-standard
- I<sup>CC</sup> category: MSI

## GENERAL DESCRIPTION

The 74HC/HCT4352 are high-speed Si-gate CMOS devices. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4352 are dual 4-channel analog multiplexers/demultiplexers with common select logic. Each multiplexer has four independent inputs/outputs ( $nY_0$  to  $nY_3$ ) and a common input/output ( $nZ$ ).

The common channel select logics include two select inputs ( $S_0$  and  $S_1$ ), an active LOW enable input ( $\bar{E}_1$ ), an active HIGH enable input ( $E_2$ ) and a latch enable input ( $\bar{L}E$ ).

With  $\bar{E}_1$  LOW and  $E_2$  HIGH, one of the four switches is selected (low impedance ON-state) by  $S_0$  and  $S_1$ . The data at the select inputs may be latched by using the active LOW latch enable input ( $\bar{L}E$ ). When  $\bar{L}E$  is HIGH, the latch is transparent. When either of the two enable inputs,  $\bar{E}_1$  (active LOW) and  $E_2$  (active HIGH), is inactive, all analog switches are turned off.

(continued on next page)

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
$t_{PZH}/t_{PZL}$	turn "ON" time $\bar{E}_1, E_2$ or $S_n$ to $V_{OS}$	$C_L = 15\text{ pF}$ $R_L = 1\text{ k}\Omega$ $V_{CC} = 5\text{ V}$	31	33	ns
$t_{PHZ}/t_{PLZ}$	turn "OFF" time $\bar{E}_1, E_2$ or $S_n$ to $V_{OS}$		20	20	ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per switch	notes 1 and 2	55	55	pF
$C_S$	max. switch capacitance independent (Y) common (Z)		5	5	pF

$V_{EE} = \text{GND} = 0\text{ V}$ ;  $T_{\text{amb}} = 25\text{ }^\circ\text{C}$ ;  $t_r = t_f = 6\text{ ns}$

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$$
 where:

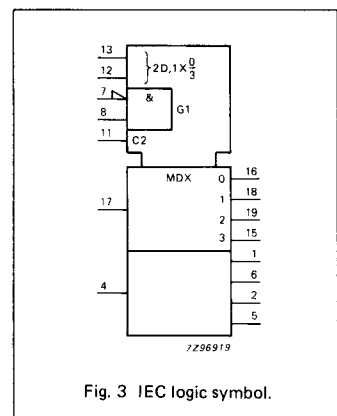
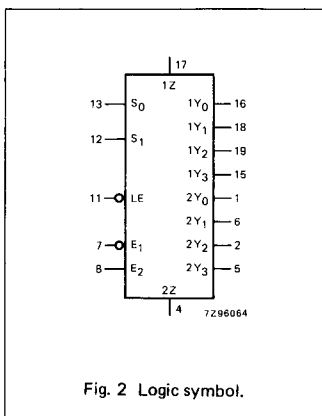
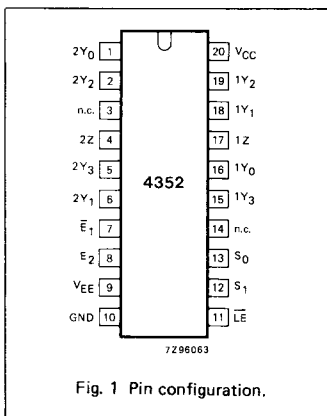
$f_i$  = input frequency in MHz  
 $f_o$  = output frequency in MHz  
 $C_L$  = output load capacitance in pF  
 $C_S$  = max. switch capacitance in pF  
 $\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$  = sum of outputs  
 $V_{CC}$  = supply voltage in V

2. For HC the condition is  $V_I = \text{GND}$  to  $V_{CC}$   
 For HCT the condition is  $V_I = \text{GND}$  to  $V_{CC} - 1.5\text{ V}$

## PACKAGE OUTLINES

20-lead DIL; plastic (SOT146).

20-lead mini-pack; plastic (SO20; SOT163A).



## PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 6, 2, 5 3, 14	2Y <sub>0</sub> to 2Y <sub>3</sub> n.c.	independent inputs/outputs not connected
7	$\bar{E}_1$	enable input (active LOW)
8	E <sub>2</sub>	enable input (active HIGH)
9	V <sub>EE</sub>	negative supply voltage
10	GND	ground (0 V)
11	$\bar{LE}$	latch enable input (active LOW)
13, 12	S <sub>0</sub> , S <sub>1</sub>	select inputs
16, 18, 19, 15	1Y <sub>0</sub> to 1Y <sub>3</sub>	independent inputs/outputs
17, 4	1Z, 2Z	common inputs/outputs
20	V <sub>CC</sub>	positive supply voltage

## GENERAL DESCRIPTION

V<sub>CC</sub> and GND are the supply voltage pins for the digital control inputs (S<sub>0</sub>, S<sub>1</sub>,  $\bar{LE}$ , E<sub>1</sub> and E<sub>2</sub>). The V<sub>CC</sub> to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs (nY<sub>0</sub> to nY<sub>3</sub>, and nZ) can swing between V<sub>CC</sub> as a positive limit and V<sub>EE</sub> as a negative limit. V<sub>CC</sub> - V<sub>EE</sub> may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V<sub>EE</sub> is connected to GND (typically ground).

## FUNCTION TABLE

INPUTS					CHANNEL ON
E <sub>1</sub>	E <sub>2</sub>	$\bar{LE}$	S <sub>1</sub>	S <sub>0</sub>	
H	X	X	X	X	none
X	L	X	X	X	none
L	H	H	L	L	nY <sub>0</sub> - nZ
L	H	H	L	H	nY <sub>1</sub> - nZ
L	H	H	H	L	nY <sub>2</sub> - nZ
L	H	H	H	H	nY <sub>3</sub> - nZ
L	H	L	X	X	*
X	X	↓	X	X	**

H = HIGH voltage level

L = LOW voltage level

X = don't care

↓ = HIGH-to-LOW  $\bar{LE}$  transition

\* Last selected channel "ON".

\*\* Selected channels latched.

## APPLICATIONS

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

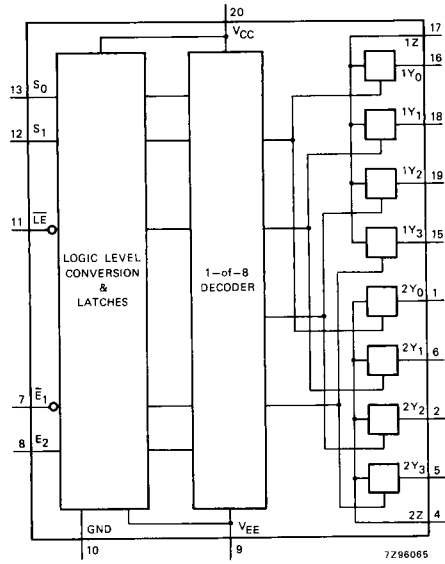


Fig. 4 Functional diagram.

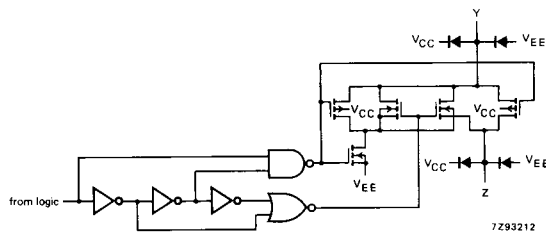


Fig. 5 Schematic diagram (one switch).

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to  $V_{EE} = \text{GND}$  (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5 \text{ V}$ or $V_I \geq V_{CC} + 0.5 \text{ V}$
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5 \text{ V}$ or $V_S \geq V_{CC} + 0.5 \text{ V}$
$\pm I_S$	DC switch current		25	mA	for $-0.5 \text{ V} < V_S < V_{CC} + 0.5 \text{ V}$
$\pm I_{EE}$	DC $V_{EE}$ current		20	mA	
$\pm I_{CC};$ $\pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	$^{\circ}\text{C}$	
$P_{tot}$	power dissipation per package				for temperature range: -40 to +125 $^{\circ}\text{C}$ 74HC/HCT
	plastic DIL		750	mW	above +70 $^{\circ}\text{C}$ : derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 $^{\circ}\text{C}$ : derate linearly with 6 mW/K
$P_S$	power dissipation per switch		100	mW	

**Note to ratings**

To avoid drawing  $V_{CC}$  current out of terminals nZ, when switch current flows in terminals nY<sub>n</sub>, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals nZ, no  $V_{CC}$  current will flow out of terminals nY<sub>n</sub>. In this case there is no limit for the voltage drop across the switch, but the voltages at nY<sub>n</sub> and nZ may not exceed  $V_{CC}$  or  $V_{EE}$ .

**RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage $V_{CC}-\text{GND}$	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
$V_{CC}$	DC supply voltage $V_{CC}-V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	$V_{EE}$		$V_{CC}$	$V_{EE}$		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	$^{\circ}\text{C}$	see DC and AC CHARACTERISTICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	$^{\circ}\text{C}$	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ $V_{CC} = 10.0 \text{ V}$

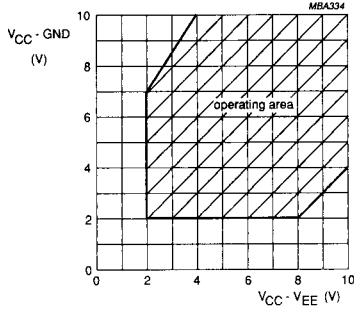


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4352.

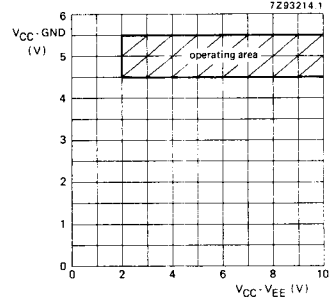


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4352.

**DC CHARACTERISTICS FOR 74HC/HCT**

For 74HC:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0$  V  
 For 74HCT:  $V_{CC} - GND = 4.5$  and  $5.5$  V;  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0$  V

SYMBOL	PARAMETER	$T_{amb}$ (°C)						UNIT	TEST CONDITIONS					
		74HC/HCT							$V_{CC}$ V	$V_{EE}$ V	$I_S$ $\mu A$	$V_{is}$	$V_I$	
		+25		-40 to +85		-40 to +125								
		min.	typ.	max.	min.	max.	min.							max.
$R_{ON}$	ON resistance (peak)		— 100 90 70	— 180 160 130		— 225 200 165		— 270 240 195	$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 4.5	0 0 0 -4.5	100 1000 1000 1000	$V_{CC}$ to $V_{EE}$	$V_{IH}$ or $V_{IL}$
$R_{ON}$	ON resistance (rail)		150 80 70 60	— 140 120 105		— 175 150 130		— 210 180 160	$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 4.5	0 0 0 -4.5	100 1000 1000 1000	$V_{EE}$	$V_{IH}$ or $V_{IL}$
$R_{ON}$	ON resistance (rail)		150 90 80 65	— 160 140 120		— 200 175 150		— 240 210 180	$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 4.5	0 0 0 -4.5	100 1000 1000 1000	$V_{CC}$	$V_{IH}$ or $V_{IL}$
$\Delta R_{ON}$	maximum $\Delta R_{ON}$ resistance between any two channels		— 9 8 6						$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 4.5	0 0 0 -4.5		$V_{CC}$ to $V_{EE}$	$V_{IH}$ or $V_{IL}$

**Notes to DC characteristics**

- At supply voltages ( $V_{CC} - V_{EE}$ ) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. There it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring  $R_{ON}$  see Fig. 8.

## DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS				
		74HC							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER	
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.						max.
V <sub>IH</sub>	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.7		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3	V	2.0 4.5 6.0 9.0				
V <sub>IL</sub>	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0			
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch OFF-state current all channels			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch ON-state current			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 11)
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND	V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>

## AC CHARACTERISTICS FOR 74HC

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)								UNIT	TEST CONDITIONS		
		74HC									V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		17 6 5 5	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 18)	
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time E <sub>1</sub> ; E <sub>2</sub> to V <sub>os</sub> LE to V <sub>os</sub>		99 36 29 25	325 65 55 46		405 81 69 58		490 98 83 69	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)	
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time S <sub>n</sub> to V <sub>os</sub>		99 36 29 25	325 65 55 46		405 81 69 58		490 98 80 69	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)	
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E <sub>1</sub> ; E <sub>2</sub> to V <sub>os</sub> LE to V <sub>os</sub>		58 21 17 21	200 40 34 40		250 50 43 50		300 60 51 60	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)	
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time S <sub>n</sub> to V <sub>os</sub>		63 23 18 24	200 40 34 40		250 50 43 50		300 60 51 60	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)	
t <sub>su</sub>	set-up time S <sub>n</sub> to LE	90 18 15 18	17 6 5 9		115 23 20 23		135 27 23 27		ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)	
t <sub>h</sub>	hold time S <sub>n</sub> to LE	5 5 5 5	-6 -2 -2 -3		5 5 5 5		5 5 5 5		ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)	
t <sub>w</sub>	LE minimum pulse width HIGH	80 16 14 16	11 4 3 4		100 20 17 20		120 24 20 24		ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)	

## DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS				
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER	
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.						max.
V <sub>IH</sub>	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5			
V <sub>IL</sub>	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5			
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	0	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch OFF-state current all channels			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch ON-state current			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 11)
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 -5.0	V <sub>CC</sub> or GND	V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V <sub>CC</sub> - 2.1V	other inputs at V <sub>CC</sub> or GND

## Note to HCT types

1. The value of additional quiescent supply current (ΔI<sub>CC</sub>) for a unit load of 1 is given here.To determine ΔI<sub>CC</sub> per input, multiply this value by the unit load coefficient shown in the table below.

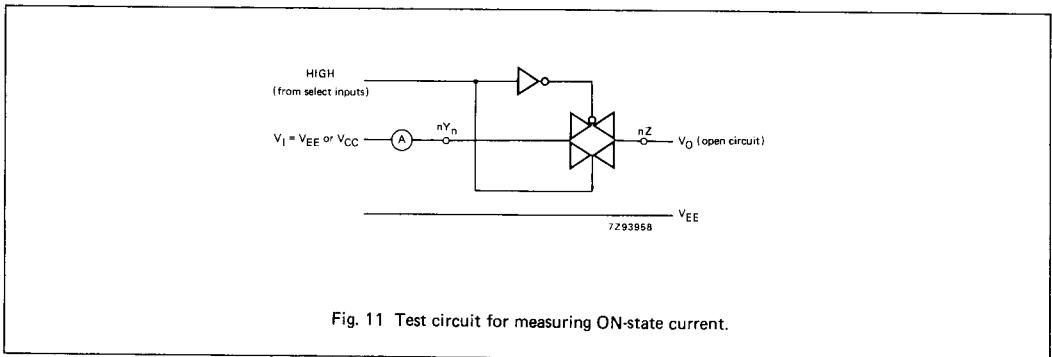
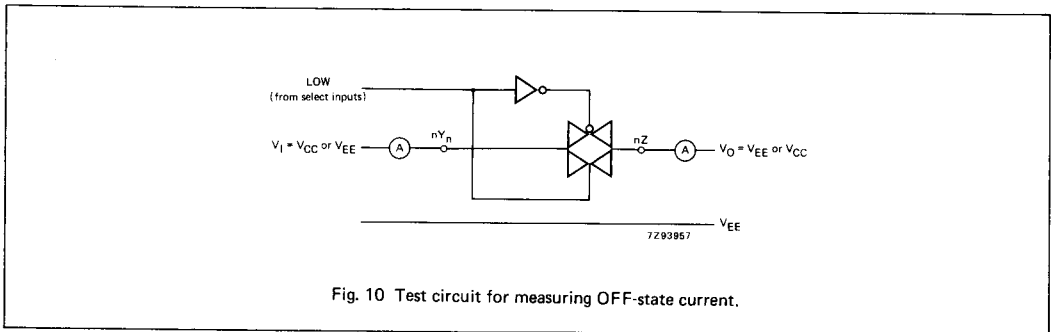
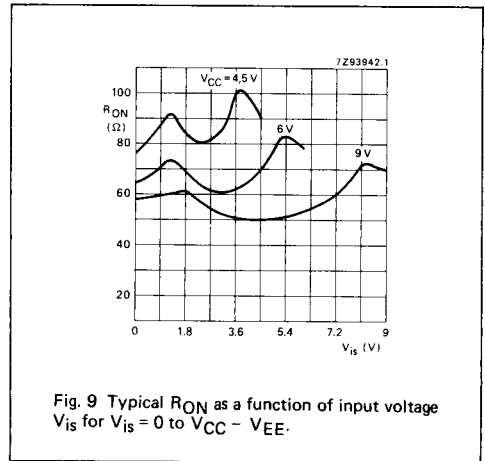
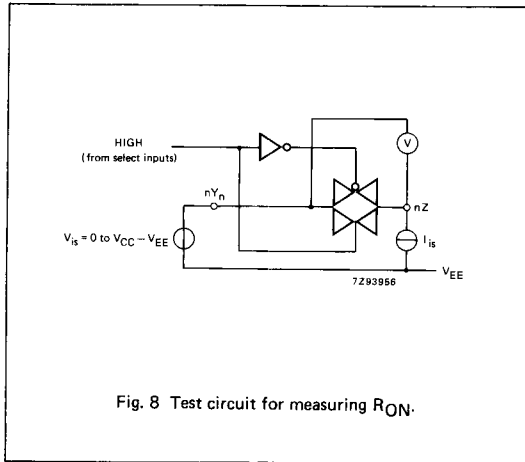
INPUT	UNIT LOAD COEFFICIENT
E <sub>1</sub> , E <sub>2</sub>	0.50
S <sub>n</sub>	0.50
LE	1.5



## AC CHARACTERISTICS FOR 74HCT

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS			
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER	
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.					max.
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		6 5	12 8		15 10		18 12	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 18)
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time E <sub>1</sub> , E <sub>2</sub> to V <sub>os</sub> LE to V <sub>os</sub>		38 28	65 46		81 58		98 69	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 18)
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time S <sub>n</sub> to V <sub>os</sub>		38 27	65 46		81 58		98 69	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E <sub>1</sub> to V <sub>os</sub> LE to V <sub>os</sub>		20 20	40 40		50 50		60 60	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E <sub>2</sub> , S <sub>n</sub> to V <sub>os</sub>		25 25	43 43		54 54		65 65	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 19)
t <sub>su</sub>	set-up time S <sub>n</sub> to LE	16 18	7 9			20 23		24 27	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)
t <sub>h</sub>	hold time S <sub>n</sub> to LE	5 5	-1 -1			5 5		5 5	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)
t <sub>w</sub>	LE minimum pulse width HIGH	16 16	3 4			20 20		24 24	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Fig. 20)



## ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ 

SYMBOL	PARAMETER	typ.	UNIT	V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>is(p-p)</sub> V	CONDITIONS
	sine-wave distortion f = 1 kHz	0.04 0.02	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	R <sub>L</sub> = 10 k $\Omega$ ; C <sub>L</sub> = 50 pF (see Fig. 14)
	sine-wave distortion f = 10 kHz	0.12 0.06	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	R <sub>L</sub> = 10 k $\Omega$ ; C <sub>L</sub> = 50 pF (see Fig. 14)
	switch "OFF" signal feed-through	-50 -50	dB dB	2.25 4.5	-2.25 -4.5	note 1	R <sub>L</sub> = 600 $\Omega$ ; C <sub>L</sub> = 50 pF f = 1 MHz (see Figs 12 and 15)
	crosstalk between any two switches/ multiplexers	-60 -60	dB dB	2.25 4.5	-2.25 -4.5	note 1	R <sub>L</sub> = 600 $\Omega$ ; C <sub>L</sub> = 50 pF; f = 1 MHz (see Fig. 16)
V <sub>(p-p)</sub>	crosstalk voltage between control and any switch (peak-to-peak value)	110 220	mV mV	4.5 4.5	0 -4.5		R <sub>L</sub> = 600 $\Omega$ ; C <sub>L</sub> = 50 pF; f = 1 MHz (E <sub>1</sub> , E <sub>2</sub> or S <sub>n</sub> , square-wave between V <sub>CC</sub> and GND, t <sub>r</sub> = t <sub>f</sub> = 6 ns) (see Fig. 17)
f <sub>max</sub>	minimum frequency response (-3dB)	160 170	MHz MHz	2.25 4.5	-2.25 -4.5	note 2	R <sub>L</sub> = 50 $\Omega$ ; C <sub>L</sub> = 10 pF (see Figs 13 and 14)
C <sub>S</sub>	maximum switch capacitance independent (Y) common (Z)	5 12	pF pF				

## Notes to AC characteristics

## General note

V<sub>is</sub> is the input voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an input.  
V<sub>os</sub> is the output voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an output.

## Notes

1. Adjust input voltage V<sub>is</sub> to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).
2. Adjust input voltage V<sub>is</sub> to 0 dBm level at V<sub>os</sub> for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

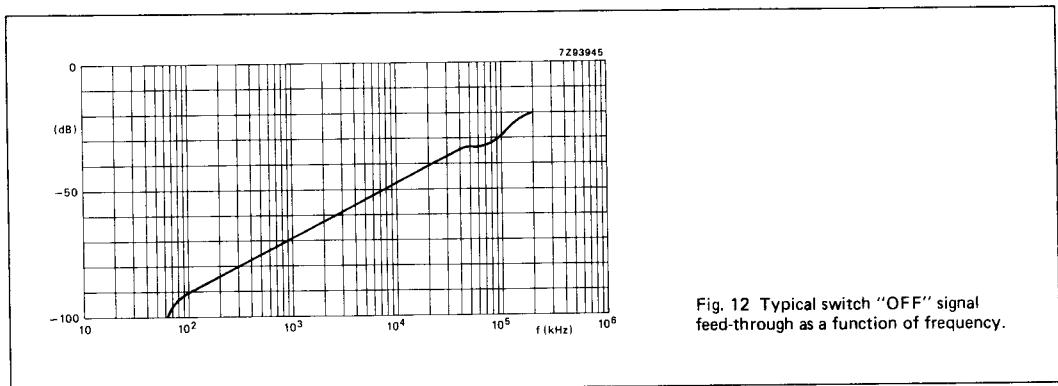
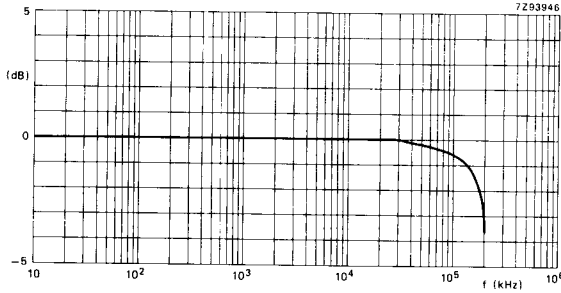


Fig. 12 Typical switch "OFF" signal feed-through as a function of frequency.



Note to Figs 12 and 13

Test conditions:  
 $V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $V_{EE} = -4.5\text{ V}$ ;  
 $R_L = 50\ \Omega$ ;  $R_{source} = 1\text{ k}\Omega$ .

Fig. 13 Typical frequency response.

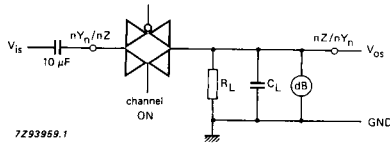


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

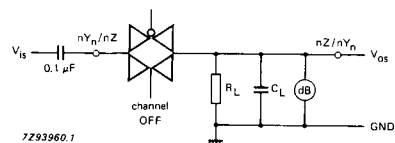


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

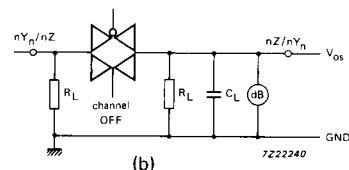
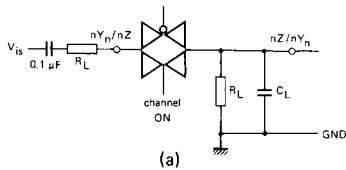


Fig. 16 Test circuits for measuring crosstalk between any two switches/multiplexers.  
 (a) channel ON condition; (b) channel OFF condition.

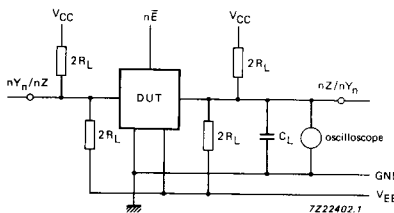
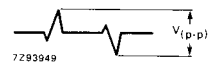


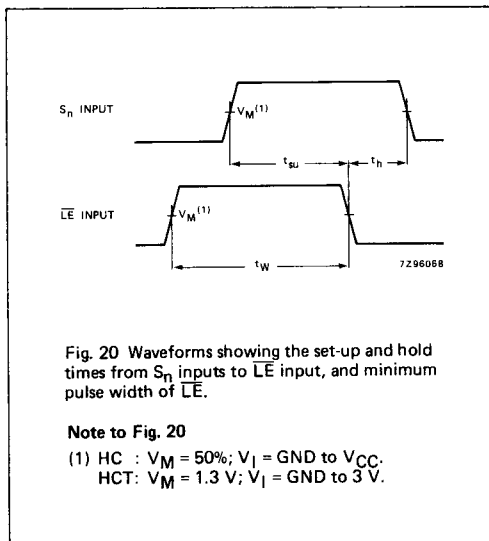
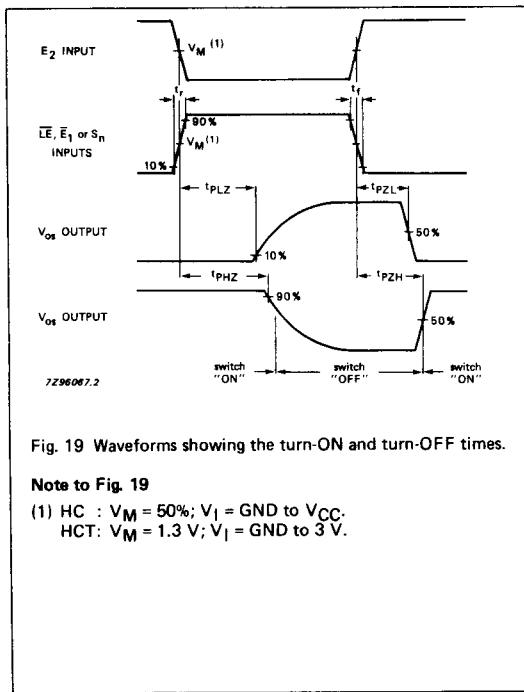
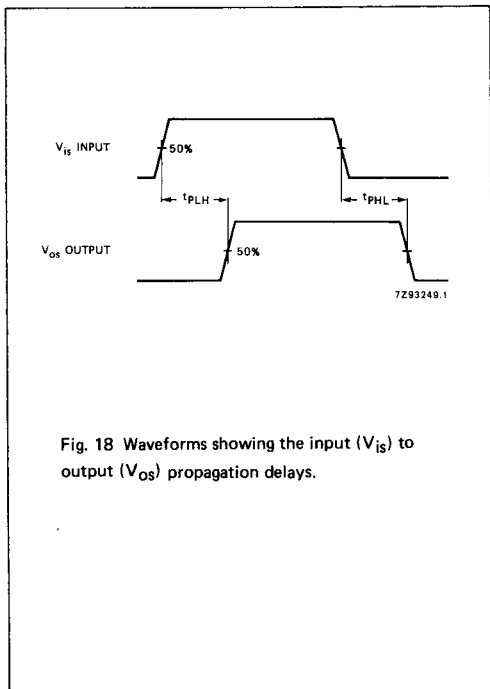
Fig. 17 Test circuit for measuring crosstalk between control and any switch.

Note to Fig. 17

The crosstalk is defined as follows  
 (oscilloscope output):



AC WAVEFORMS



TEST CIRCUIT AND WAVEFORMS

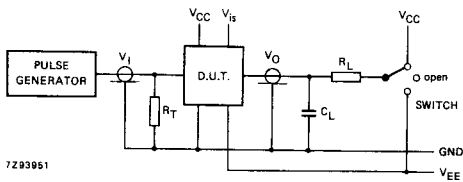


Fig. 21 Test circuit for measuring AC performance.

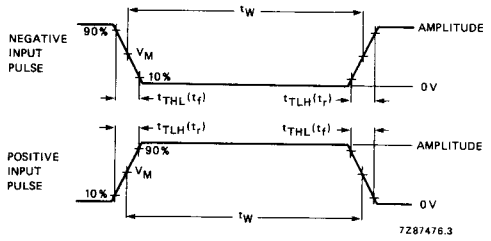


Fig. 22 Input pulse definitions.

Conditions

TEST	SWITCH	V <sub>is</sub>
t <sub>PZH</sub>	V <sub>EE</sub>	V <sub>CC</sub>
t <sub>PZL</sub>	V <sub>CC</sub>	V <sub>EE</sub>
t <sub>PHZ</sub>	V <sub>EE</sub>	V <sub>CC</sub>
t <sub>PLZ</sub>	V <sub>CC</sub>	V <sub>EE</sub>
others	open	pulse

FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> ; PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Definitions for Figs 21 and 22:

- C<sub>L</sub> = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).
- R<sub>T</sub> = termination resistance should be equal to the output impedance Z<sub>O</sub> of the pulse generator.
- t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint on t<sub>r</sub>, t<sub>f</sub> with 50% duty factor.